

# HD74LV06A

## Hex Inverter Buffers / Drivers with Open Drain Outputs

REJ03D0230-0500Z (Previous ADE-205-296B (Z)) Rev.5.00 May 21, 2004

### **Description**

The HD74LV06A has six inverter buffers / drivers with open drain outputs in a 14-pin package.

Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

### **Features**

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
- All outputs  $V_0$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V)
- All outputs  $V_0$  (Max.) = 5.5 V (@ $V_{CC}$  = 2.0 V to 5.5 V, Output "Z" state)
- Typical  $V_{OL}$  ground bounce < 0.8 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Output current  $\pm 8$  mA (@V<sub>CC</sub> = 3.0 V to 3.6 V),  $\pm 16$  mA (@V<sub>CC</sub> = 4.5 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV06AFPEL	SOP-14 pin(JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
HD74LV06ARPEL	SOP-14 pin(JEDEC)	FP-14DNV	RP	EL (2,500 pcs/reel)
HD74LV06ATELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

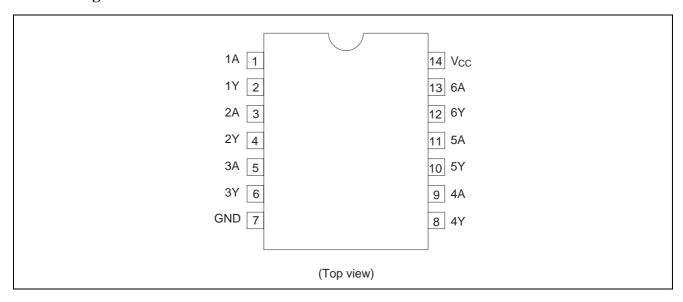
Note: Please consult the sales office for the above package availability.

### **Function Table**

Input A	Output Y
L	Z
Н	L

Note: H: High level
L: Low level
Z: High impedance

### **Pin Arrangement**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V	
Input voltage range*1	VI	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	$-0.5$ to $V_{CC} + 0.5$	V	Output: Z or L
		-0.5 to 7.0		V <sub>CC</sub> : OFF
Input clamp current	I <sub>IK</sub>	-20	mA	V <sub>I</sub> < 0
Output clamp current	lok	±50	mA	V <sub>O</sub> < 0
Continuous output current	lo	±35	mA	$V_O = 0$ to $V_{CC}$
Continuous current through	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
V <sub>CC</sub> or GND				
Maximum power dissipation at	P <sub>T</sub>	785	mW	SOP
Ta = 25°C (in still air)* <sup>3</sup>		500		TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

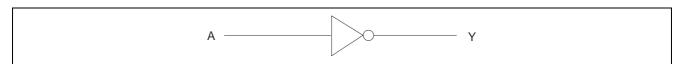
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 7.0 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

## **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	2.0	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	5.5	V	
Output current	I <sub>OL</sub>	_	50	μΑ	$V_{CC} = 2.0 \text{ V}$
		_	2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	8		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	16		V <sub>CC</sub> = 4.5 to 5.5 V
Input transition rise or fall rate	Δt / Δν	0	200	ns/V	V <sub>CC</sub> = 2.3 to 2.7 V
		0	100		V <sub>CC</sub> = 3.0 to 3.6 V
		0	20		V <sub>CC</sub> = 4.5 to 5.5 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

### Logic Diagram



### **DC Electrical Characteristics**

 $Ta = -40 \text{ to } 85^{\circ}C$ 

Item	Symbol	V <sub>CC</sub> (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	$V_{IH}$	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC}\times 0.7$	_	_	_	
		3.0 to 3.6	$V_{CC}\times 0.7$	_	_	_	
		4.5 to 5.5	$V_{CC}\times 0.7$	_	_	_	
	V <sub>IL</sub>	2.0	_	_	0.5	<u> </u>	
		2.3 to 2.7	_	_	$V_{CC}\!\times\!0.3$	_	
		3.0 to 3.6	_	_	$V_{CC} \times 0.3$	_	
		4.5 to 5.5	_	_	$V_{\text{CC}} \times 0.3$		
Output voltage	$V_{OL}$	Min to Max	_	_	0.1	V	$I_{OL} = 50 \mu A$
		2.3	_	_	0.4	_	$I_{OL} = 2 \text{ mA}$
		3.0	_	_	0.44	_	$I_{OL} = 8 \text{ mA}$
		4.5	_	_	0.55		I <sub>OL</sub> = 16 mA
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off state output current	l <sub>OZ</sub>	Min to Max	_	_	±2.5	μΑ	$V_0 = 5.5 \text{ V}$
Quiescent supply current	Icc	5.5	_	_	20	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	l <sub>OFF</sub>	0	_	_	5	μΑ	$V_1$ or $V_0 = 0$ to 5.5 V
Input capacitance	C <sub>IN</sub>	3.3	_	2.3	_	pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

## **Switching Characteristics**

 $V_{CC}=2.5\pm0.2~V$ 

		Ta =	25°C		Ta = -	40 to 85°C		Test FROM		TO
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	4.7	10.4	1.0	13.0	ns	C <sub>L</sub> = 15 pF	Α	Υ
delay time		_	9.5	15.2	1.0	18.0	_	C <sub>L</sub> = 50 pF		
	t <sub>PHL</sub>	_	5.4	10.4	1.0	13.0		C <sub>L</sub> = 15 pF		
		_	7.9	15.2	1.0	18.0	_	C <sub>L</sub> = 50 pF		

 $V_{CC} = 3.3 \pm 0.3 \ V$ 

Item	Symbol	Ta =	25°C		$Ta = -40 \text{ to } 85^{\circ}C$		Unit	Test	FROM	TO
		Min	Тур	Max	Min	Max		Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	4.0	7.1	1.0	8.5	ns	C <sub>L</sub> = 15 pF	Α	Υ
delay time		_	7.3	10.6	1.0	12.0		C <sub>L</sub> = 50 pF	<u></u>	
	t <sub>PHL</sub>	_	4.3	7.1	1.0	8.5	_	C <sub>L</sub> = 15 pF		
		_	5.8	10.6	1.0	12.0		C <sub>L</sub> = 50 pF		

 $V_{CC} = 5.0 \pm 0.5~V$ 

		Ta =	25°C		Ta = -4	10 to 85°C		Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	3.3	5.5	1.0	6.5	ns	C <sub>L</sub> = 15 pF	Α	Υ
delay time		_	5.6	7.5	1.0	8.5	_	C <sub>L</sub> = 50 pF		
	t <sub>PHL</sub>	_	3.4	5.5	1.0	6.5		C <sub>L</sub> = 15 pF		
		_	4.1	7.5	1.0	8.5		C <sub>L</sub> = 50 pF		

## **Operating Characteristics**

 $C_L = 50 \text{ pF}$ 

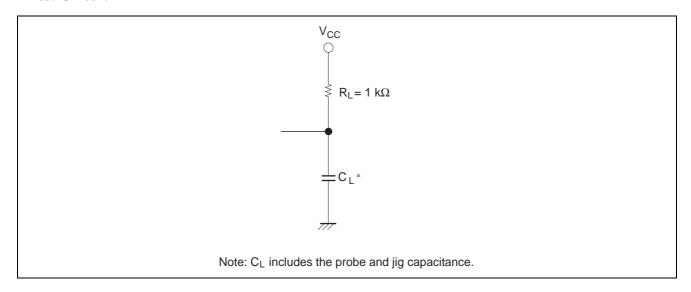
			Ta = 25°C				
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	$C_{PD}$	3.3	_	9.6	_	pF	f = 10 MHz
		5.0	_	11.4	_		

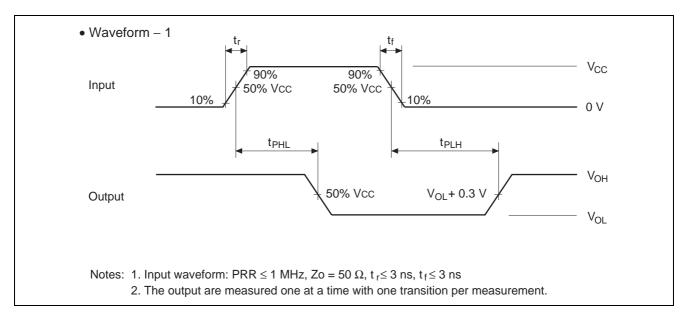
## **Noise Characteristics**

 $C_L = 50 \ pF$ 

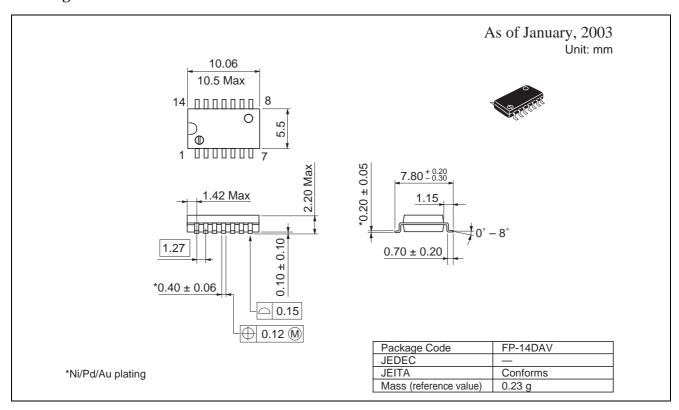
		Ta = 25	5°C						
Item	Symbol	V <sub>CC</sub> (V)	Min Typ		Typ Max		Test Conditions		
Quiet output, maximum dynamic V <sub>OL</sub>	$V_{OL\ (P)}$	3.3	_	0.3	0.8	V			
Quiet output, minimum dynamic V <sub>OL</sub>	V <sub>OL (V)</sub>	3.3	_	-0.1	-0.8	V			
High-level dynamic input voltage	V <sub>IH</sub> (D)	3.3	2.31	_	_	V			
Low-level dynamic input voltage	V <sub>IL (D)</sub>	3.3	_	_	0.99	V			

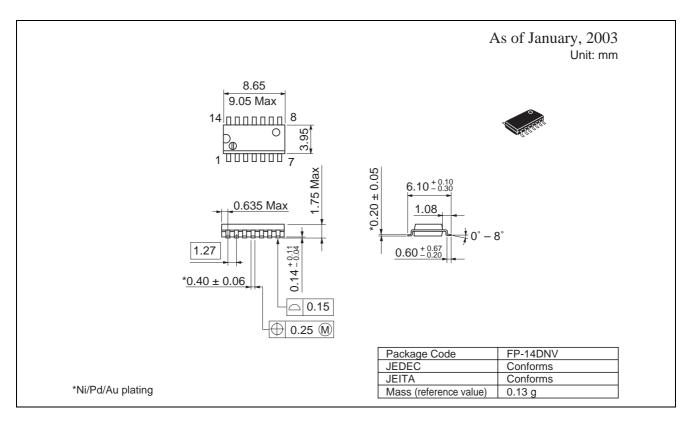
### **Test Circuit**

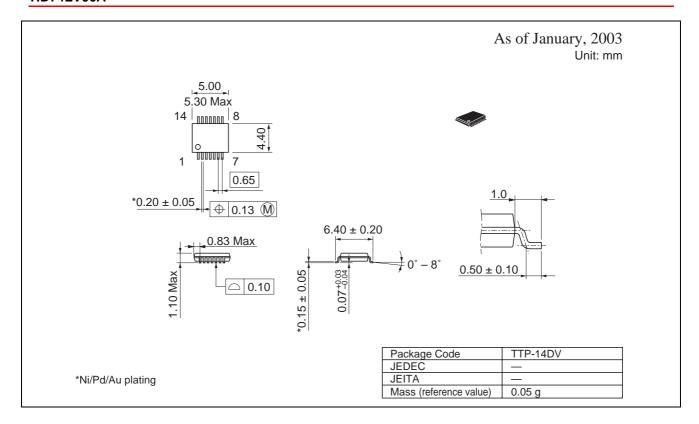




### **Package Dimensions**







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